MOSFETs Silicon N-Channel MOS (U-MOSVII)

TPCA8087

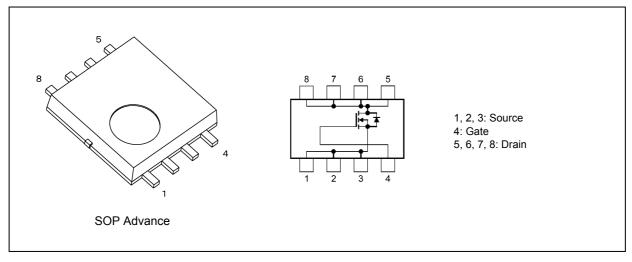
1. Applications

- Notebook PCs
- Mobile Handsets

2. Features

- (1) Small footprint due to a small and thin package
- (2) Low drain-source on-resistance: $R_{DS(ON)} = 1.5 \text{ m}\Omega$ (typ.) ($V_{GS} = 10 \text{ V}$)
- (3) Low leakage current: I_{DSS} = 10 μ A (max) (V_{DS} = 30 V)
- (4) Enhancement mode: V_{th} = 1.3 to 2.3 V (V_{DS} = 10 V, I_{D} = 1.0 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25^{\circ}C$ unless otherwise specified)

| Characteris | Symbol | Rating | Unit | | |
|-------------------------------|-------------------------|----------|------------------|------------|----|
| Drain-source voltage | | | V _{DSS} | 30 | V |
| Gate-source voltage | | | V _{GSS} | ±20 | |
| Drain current (DC) | | (Note 1) | Ι _D | 56 | A |
| Drain current (pulsed) | | (Note 1) | I _{DP} | 168 | |
| Power dissipation | (T _c = 25°C) | | PD | 70 | W |
| Power dissipation | (t = 10 s) | (Note 2) | PD | 2.8 | W |
| Power dissipation | (t = 10 s) | (Note 3) | PD | 1.6 | W |
| Single-pulse avalanche energy | | (Note 4) | E _{AS} | 407 | mJ |
| Avalanche current | | | I _{AR} | 56 | A |
| Channel temperature | | | T _{ch} | 150 | °C |
| Storage temperature | | | T _{stg} | -55 to 150 | 7 |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

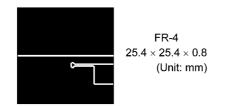
| Characteristics | | | | Max | Unit |
|---------------------------------------|-------------------------|----------|-----------------------|------|------|
| Channel-to-case thermal resistance | (T _c = 25°C) | | R _{th(ch-c)} | 1.78 | °C/W |
| Channel-to-ambient thermal resistance | (t = 10 s) | (Note 2) | R _{th(ch-a)} | 44.6 | |
| Channel-to-ambient thermal resistance | (t = 10 s) | (Note 3) | R _{th(ch-a)} | 78.1 | °C/W |

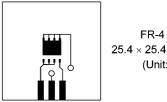
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4: V_{DD} = 24 V, T_{ch} = 25°C (initial), L = 0.1 mH, R_G = 1 Ω , I_{AR} = 56 A





 $25.4\times25.4\times0.8$ (Unit: mm)

Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)

Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

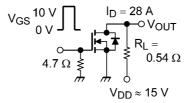
6. Electrical Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

6.1. Static Characteristics

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|----------------------|---|-----|------|------|------|
| Gate leakage current | I _{GSS} | V_{GS} = ±20 V, V_{DS} = 0 V | _ | _ | ±0.1 | μA |
| Drain cut-off current | I _{DSS} | V _{DS} = 30 V, V _{GS} = 0 V | — | _ | 10 | |
| Drain-source breakdown voltage | V _{(BR)DSS} | I _D = 10 mA, V _{GS} = 0 V | 30 | _ | _ | V |
| | V _{(BR)DSX} | I _D = 10 mA, V _{GS} = -20 V | 15 | _ | _ | |
| Gate threshold voltage | V _{th} | V _{DS} = 10 V, I _D = 1.0 mA | 1.3 | _ | 2.3 | |
| Drain-source on-resistance | R _{DS(ON)} | V _{GS} = 4.5 V, I _D = 28 A | | 1.9 | 2.3 | mΩ |
| | | V _{GS} = 10 V, I _D = 28 A | | 1.5 | 1.9 | |

6.2. Dynamic Characteristics

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|------------------|--|-----|------|-----|------|
| Input capacitance | C _{iss} | V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz | _ | 6400 | _ | pF |
| Reverse transfer capacitance | C _{rss} | | _ | 360 | — | |
| Output capacitance | C _{oss} | | _ | 1200 | _ | |
| Switching time (rise time) | t _r | See Figure 6.2.1. | _ | 5.7 | _ | ns |
| Switching time (turn-on time) | t _{on} | | | 16 | _ | |
| Switching time (fall time) | t _f | | | 11 | _ | |
| Switching time (turn-off time) | t _{off} | | _ | 73 | _ | |



Duty \leq 1%, $t_W =$ 10 μs

Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics

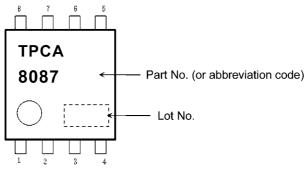
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--|------------------|--|-----|------|-----|------|
| Total gate charge (gate-source plus gate-drain) | Qg | $V_{DD} \approx 24$ V, V_{GS} = 10 V, I_D = 56 A | | 91 | — | nC |
| Gate-source charge 1 | Q _{gs1} | | _ | 20 | _ | |
| Gate-drain charge | Q _{gd} | | _ | 12 | _ | |

6.4. Source-Drain Characteristics

| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---------------------------------|---------|------------------|---|-----|------|------|------|
| Pulsed reverse drain current (I | Note 5) | I _{DRP} | — | | _ | 168 | Α |
| Diode forward voltage | | V _{DSF} | I _{DR} = 56 A, V _{GS} = 0 V | | _ | -1.2 | V |

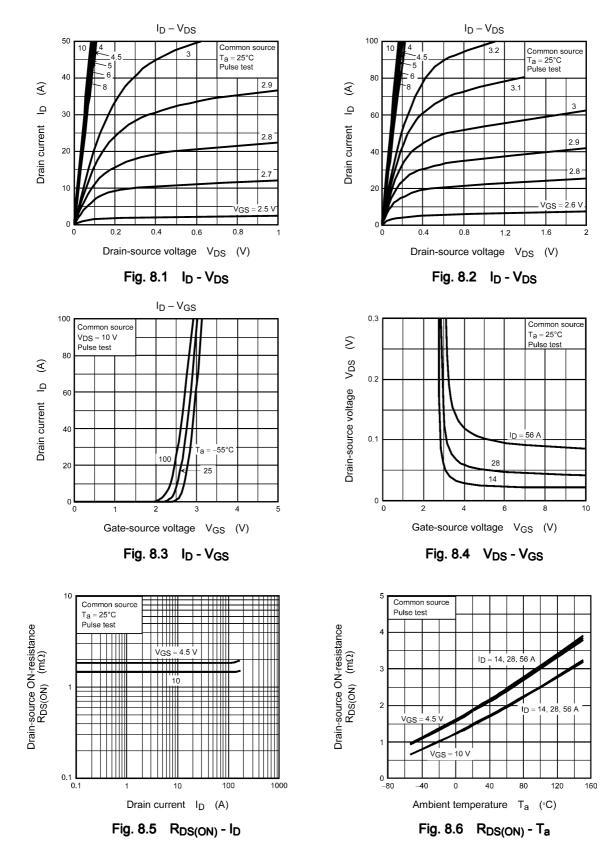
Note 5: Ensure that the channel temperature does not exceed 150°C.

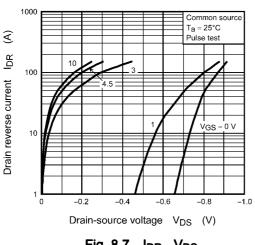
7. Marking



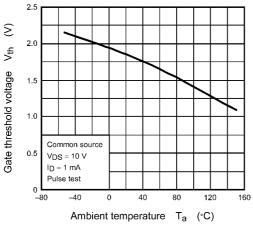


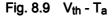
8. Characteristics Curves (Note)

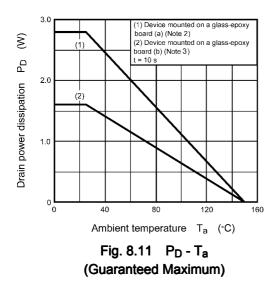


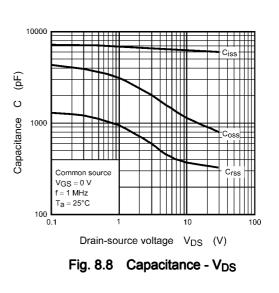












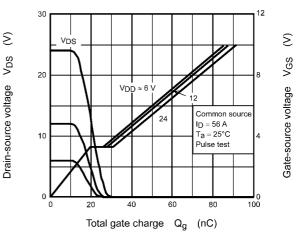
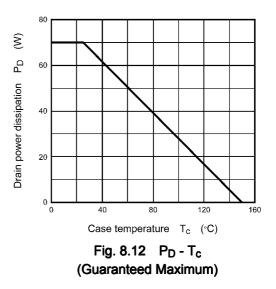
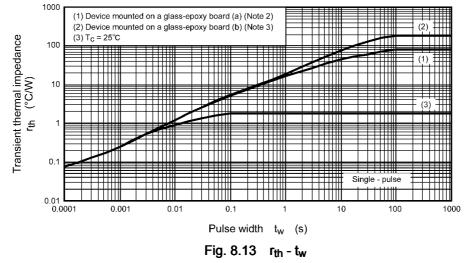


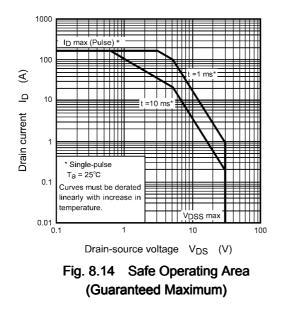
Fig. 8.10 Dynamic Input/Output Characteristics









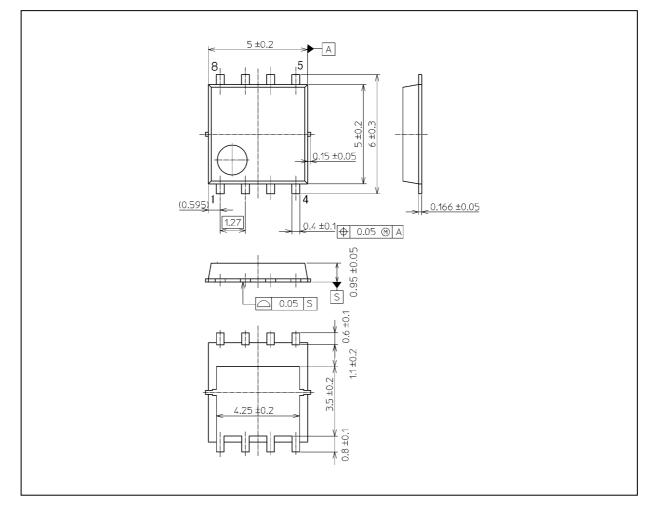


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

TPCA8087

Package Dimensions

Unit: mm



Weight: 0.069 g (typ.)

Package Name(s)

TOSHIBA: 2-5Q1S

Nickname: SOP Advance

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